

Type	L #	Hits	Search Text	DBs	Time Stamp	Err ors
					n o n i t s i t o	E r r C o r m D e f o r s n i t n s i t o
1	BRS L2	0	1 and silsesquioxane	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/12/30 11:57	0
2	BRS L3	1842	silsesquioxane	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/12/30 11:57	0
3	BRS L5	0	4 and (ito or (indium adj tin adj oxide))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/12/30 11:58	0
4	BRS L6	73	3 and (plastic same substrate)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/12/30 12:53	0
5	BRS L7	2	6 and (ito or (indium adj tin adj oxide))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/12/30 11:58	0
6	BRS L8	295	3 and precursor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/12/30 12:54	0
7	BRS L9	42	3 and (precursor same alkyl)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/12/30 12:58	0
8	BRS L10	3	3 and (precursor same (alkyl adj methyl))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/12/30 12:59	0

Type	L #	Hits	Search Text	DBs	Time Stamp	Errors
9	BRS	L4	8 3 and mylar	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/12/30 13:08	0
10	BRS	L11	0 1 and hsq	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/12/30 13:08	0
11	BRS	L1	112 ITO same mylar	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/12/30 13:19	0
12	BRS	L12	22 silsesquioxane same gate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/12/30 13:21	0